Atomic layer deposition with rotary reactor for uniform hetero-junction photocatalyst, g-C₃N₄@TiO₂ core–shell structures†

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A heterojunction of TiO₂ grown on g-C₃N₄ particles is demonstrated using atomic layer deposition (ALD), equipped with a specifically designed rotary reactor for maintaining stable mechanical dispersion of g-C₃N₄ particles during ALD. The photocatalytic activity of the g-C₃N₄@ALD-TiO₂ core–shell composites was examined using the degradation of rhodamine B dye under visible light irradiation. The optimal composite with 5 ALD cycles of TiO₂ exhibited the highest photocatalytic reaction rate constant among the composites with a range of ALD cycles from 2 to 200 cycles, which was observed to be 3 times higher than that of pristine g-C₃N₄ and 2 times higher than that of g-C₃N₄@TiO₂ composite prepared using a simple impregnation method. The ALD-TiO₂ were well-dispersed on the g-C₃N₄ surface, while TiO₂ nanoparticles were agglomerated onto the g-C₃N₄ in the g-C₃N₄@TiO₂ composite prepared by the impregnation method. This created uniform and stable heterojunctions between the g-C₃N₄ and TiO₂, thus, enhancing the photocatalytic activity.

1. Introduction

As various environmental issues from pollutants and alternative energy resources have emerged, research to identify solutions that address these problems has received much attention. Among a variety of suggested solutions, photocatalysts have attracted intensive interest due to their potential for photodecomposition of organic pollutants and hydrogen generation from solar light. Ever since Wang et al. used graphitic carbon nitride (g-C₃N₄) as a metal-free photocatalyst to generate hydrogen from water utilizing solar radiation in 2009, g-C₃N₄ has been widely studied as a promising photocatalyst. g-C₃N₄ is a two-dimensional, π-conjugated polymeric semiconductor which exhibits photocatalytic activity from visible light with an energy bandgap of ~2.7 eV. g-C₃N₄ is physicochemically stable, environmentally friendly, and easily synthesized using cheap precursors. The photocatalytic activity of g-C₃N₄, however, is limited by the rapid recombination of photogenerated electron–hole pairs. To enhance the photocatalytic performance of g-C₃N₄, various methods have been investigated, such as nanostructure design, crystal structure engineering, doping, and coupling with other semiconductors. Among these methods, coupling with other semiconductor has been identified as one of the most efficient methods to lower the recombination rate of photogenerated charge carriers. As a result, previous researchers have coupled g-C₃N₄ with other semiconductors, including Bi₂WO₆, BiVO₄, TaON, CdS, ZnO, and TiO₂, and their results showed improved photocatalytic activity owing to efficient charge separation. This semiconductor heterostructure design has been proved as a promising strategy for photocatalytic dye degradation through a number of publications.

In the early stages of research on g-C₃N₄, we demonstrated the potential of a high-efficiency photocatalyst using a g-C₃N₄@TiO₂ heterojunction composite with chemical stability and non-toxicity. Various attempts to coat TiO₂ on g-C₃N₄ are documented in the literature; synthesis methods such as ball-milling, the impregnation method, hydrolysis, and solvothermal techniques have been employed to form g-C₃N₄@TiO₂ composites. However, when utilizing the solid-state mixing and impregnation methods, it is difficult to make a uniform heterojunction between pre-synthesized g-C₃N₄ and TiO₂. For the hydrolysis method, it is hard to achieve the formation of well-distributed TiO₂ particles on the surface of g-C₃N₄ due to the rapid hydrolysis reaction. Therefore, the solvothermal method has been widely used to produce a uniform coating by utilizing in situ TiO₂ growth on the surface of g-C₃N₄. However, practical problems also exist in liquid phase synthesis processes like the solvothermal
method; it is difficult to precisely control the size and concentration of TiO$_2$ particles in the coating. Furthermore, still problematic are common issues of solvothermal method such as residual impurities and time-consuming process. Cleaning, centrifugation, and drying steps must be performed after the main synthesis process.

In this work, atomic layer deposition (ALD) was introduced to resolve the aforementioned problems in the synthesis of g-C$_3$N$_4$ based heterojunction composites. ALD is a vapor deposition method consisting of self-limiting surface chemical reactions. Alternating pulses of a precursor and an oxidant (denoted as A, B sequence, respectively) are supplied into the ALD reactor, and surface reactions occur on the surface of the substrate. This AB reaction cycle runs repeatedly in a sequence,$^{33}$ which can achieve ultrathin and uniform film deposition by controlling the number of AB cycles.$^{33}$ Recently, reports on particle coating via ALD have increased.$^{37}$ Longrie et al. proved a pinhole-free and conformal Al$_2$O$_3$ film coating on ZnO nanoparticles.$^{38}$ Hakim et al. reported the conformal Al$_2$O$_3$ coating on TiO$_2$ to suppress the phototoxicity of TiO$_2$ in sunscreen applications.$^{39,40}$ Here, introduction of an ALD to form a TiO$_2$ coating on the surface of g-C$_3$N$_4$ (g-C$_3$N$_4$@ALD-TiO$_2$) allows for precise size control of the TiO$_2$ nanoparticles, low concentrations of impurity residues, and a simple synthesis process. However, the general ALD system is designed for the deposition process on fixed Si wafer. Therefore, the ALD system used in this work is equipped with specially designed rotary reactor, which provides general ALD system is designed for the deposition process on fixed Si wafer. Therefore, the ALD system used in this work is equipped with specially designed rotary reactor, which provides stable mechanical dispersion of g-C$_3$N$_4$ particles in the reactor for uniform coating of TiO$_2$. As a result, the photocatalytic activity of the synthesized composite was enhanced by producing stable, uniform, and intimate heterojunctions between g-C$_3$N$_4$ and TiO$_2$. A photocatalytic degradation experiment of rhodamine b (RhB) was utilized to probe the enhancement in the photocatalytic activity of g-C$_3$N$_4$@ALD-TiO$_2$ composite, and various physicochemical analyses were conducted on the composite. A g-C$_3$N$_4$@TiO$_2$ composite synthesized using a simple impregnation method was also prepared to be used as a control group.

2. Experimental

2.1. Preparation of g-C$_3$N$_4$

Bulk g-C$_3$N$_4$ was synthesized using a simple pyrolysis method.$^{35}$ 10 g of urea was ground in a mortar and put into a crucible covered with aluminum foil. The crucible was calcined at 550 °C for 4 h at a heating rate of 10 °C per min in a muffle furnace. The yellow product that was obtained was ground into a powder for further use.

2.2. Preparation of g-C$_3$N$_4$@TiO$_2$ composite

The g-C$_3$N$_4$@TiO$_2$ composites were prepared using ALD with a specially designed rotary reactor. The pristine g-C$_3$N$_4$ powder was loaded into the rotary reactor (Atomic shell, CN-1 Co. Ltd., Korea), which was connected to ALD equipment. TiO$_2$ was grown on the g-C$_3$N$_4$ using titanium isopropoxide (Ti[OCH(CH$_3$)$_2$]$_4$, TTIP) and deionized (DI) water as the metal precursor and oxygen source, respectively. The temperature of the reactor was kept at 250 °C. The rotation speed of the rotary reactor was maintained at 60 rpm. N$_2$ gas at 200 sccm was used for the purge process. The sequence of an ALD cycle is as follows: TTIP pulse, reactor isolation, N$_2$ purge, H$_2$O pulse, reactor isolation, and N$_2$ purge. We introduced the reactor isolation step to enhance the surface reaction on g-C$_3$N$_4$. g-C$_3$N$_4$@TiO$_2$ composites with 2, 5, 20, 50, and 200 cycles of TiO$_2$ ALD were prepared. The prepared g-C$_3$N$_4$@TiO$_2$ composites were calcined at 400 °C for 1 h in an atmosphere using a muffle furnace. For comparison, g-C$_3$N$_4$@TiO$_2$ composites were also prepared using a simple impregnation method.$^{41}$ In a typical procedure, 0.3 g of g-C$_3$N$_4$ was added to methanol (80 mL), and the solution was sonicated for 30 min. Then, 0.0375 g of TiO$_2$ nanoparticles (P25) was added to the solution and stirred in a fume hood for 24 h. Next, the solution was dried in a drying oven at 60 °C for 24 h. We denote pristine g-C$_3$N$_4$ as GCN; the g-C$_3$N$_4$@TiO$_2$ composites obtained by ALD are denoted as GT2, GT5, GT20, GT50, and GT200 (GTs) according to the number of ALD cycles; and the composites obtained from the simple impregnation method are denoted as GTC.

2.3. Materials characterizations

The morphology of the composites was observed using energy dispersive X-ray spectroscopy (EDS) attached to a field emission-scanning electron microscope (FESEM, HITACHI-S4800) and a high-resolution-transmission electron microscope (HRTEM, JEM-2100F). Nitrogen adsorption–desorption isotherms were obtained on a Micrometrics ASAP 2010 system to measure the Brunauer–Emmett–Teller (BET) specific surface area and porosity of the composites. The crystalline structure of the composites was examined with an X-ray diffractometer (XRD, Rigaku-Dmax 2500) using Cu-K$_\alpha$ radiation (λ = 0.15405 nm, 40 kV, 100 mA). Fourier transform-infrared (FT-IR) spectra of the composites were collected using an attenuated total reflectance FT-IR spectrometer (Thermo Fisher Scientific-NICOLET iS10). UV-Vis diffuse reflectance spectroscopy (DRS) analysis of the composites was carried out on a UV-Vis spectrophotometer (JASCO V-650) using BaSO$_4$ as a reference. Photoluminescence (PL) spectra of the composites were acquired using HORIBA-LabRAM HR to analyze the recombination behavior of the photo-generated carriers. An excitation wavelength of 320 nm was used, and PL emission spectra were obtained under λ = 350–700 nm.

2.4. Evaluation of photocatalytic activity

The photocatalytic activities of the samples were evaluated using the degradation of RhB under visible light irradiation to examine the effect of ALD TiO$_2$. RhB (0.0072 g) was added to 1 L DI water and stirred in the dark for 1 h. 30 mg of a photocatalyst were transferred into 200 mL of the aqueous RhB solution and stirred in the dark for 1 h to establish an adsorption–desorption equilibrium. Then, the reaction slurry was irradiated under visible light for 2 h using a 100 W halogen lamp with UV-absorbing glass filter (HI-Spot 95) obtained from Osram Sylvania Inc. Luminous intensity is 80 klux (~11.7 mW cm$^{-2}$ or
7400 foot-candle), which was measured with a lux meter (TES-1339 Light Meter Pro) at several points. Each suspension was collected at 20 minute intervals. We recorded the changes in concentration of the suspension versus irradiation time by observing the maximum absorption spectra using a JASCO V-550 UV-Vis spectrophotometer. To determine the active species during the photocatalytic degradation of the RhB dye, benzoquinone (BQ, 1 mM), EDTA-2Na (1 mM), and isopropanol alcohol (IPA, 5 mM) were used to trap the superoxide radical (O$_2^-$), the hole (h$^+$) scavenger, and the hydroxyl radical (OH$^-$) scavenger, respectively.

3. Results and discussion

SEM images of GCN, GT200, and GTC are shown in Fig. 1a, b, and c, respectively. Morphological changes between GT200 and GCN were difficult to observe with SEM due to resolution limits. However, the GTC prepared with the simple impregnation method in Fig. 1c exhibited agglomerates of TiO$_2$ particles on the g-C$_3$N$_4$ surface. SEM-EDS point analyses further confirmed the presence of agglomerated TiO$_2$ particles in the GTC samples (Fig. S1). Fig. 1d, e, and f show the SEM images and corresponding EDS elemental (N and Ti) mapping results for GT50, respectively. The coincidence of the g-C$_3$N$_4$ particle shape (or N mapping results) with the Ti mapping results suggests a homogeneous coating of ALD TiO$_2$ on g-C$_3$N$_4$. The concentration of TiO$_2$ on the g-C$_3$N$_4$ can be estimated using the Ti/N ratio, which was measured with SEM-EDS and TEM-EDS and plotted as a function of the number of ALD cycles, as shown in Fig. 1g. For both cases the Ti/N wt% ratio increased linearly with the number of TiO$_2$ ALD cycles, which suggests that ALD TiO$_2$ was successfully grown on g-C$_3$N$_4$.

Fig. 1h shows the XRD patterns of GCN, GTs, and GTC. GCN exhibits two characteristic diffraction peaks which are 13.1°, 27.6°, corresponding to the in-plane ordering of the tri-s-triazine unit for the (001) plane and the interlayer-stacking of the aromatic system for the (002) plane of g-C$_3$N$_4$, respectively. When more than 20 TiO$_2$ ALD cycles were used, we observed a gradual decrease in the intensity of the g-C$_3$N$_4$ (001) plane peak, and anatase TiO$_2$ (101), (004), (200), (105), (211), and (204) peaks clearly appeared at GT200. The TiO$_2$ crystalline structure in the GTs with <200 ALD cycles was hardly detected by XRD because ALD TiO$_2$ exhibits nanocrystalline particle-like growth on the g-C$_3$N$_4$, and layer growth only occurs at the edge of the g-C$_3$N$_4$, which is discussed in more detail with the HRTEM analysis. For GTC, the peaks of g-C$_3$N$_4$ and anatase TiO$_2$ were clearly observed.

The HRTEM image in Fig. 2a shows the smooth surface of GCN. The amorphous structure of GCN was confirmed using a magnified image in the inset of Fig. 2a. Although TiO$_2$ particles are scarce in the GT50 shown in Fig. 2b, nano-crystalline structures with several nm in size were observed in the magnified HRTEM structure in Fig. 2c, where the $d$-spacing is 0.23 nm and corresponds to the (001) plane in anatase TiO$_2$. In Fig. 2d, it is apparent that the conformal TiO$_2$ layer is coated along the edge of the g-C$_3$N$_4$ in the GT200 sample, and the TiO$_2$ nanoparticles are well distributed on the g-C$_3$N$_4$ surface. Furthermore, the magnified HRTEM image obtained from the area marked with a yellow box in Fig. 2d (Fig. 2e) confirmed that the interplanar distance of TiO$_2$ coated on the surface and along the edge of the g-C$_3$N$_4$ was also 0.23 nm, which coincides with the $d$-spacing of the (001) plane of anatase TiO$_2$. The fringes on the g-C$_3$N$_4$ with a lattice spacing of 0.34 nm in the orange dashed circle are consistent with that of the (101) plane of anatase TiO$_2$. Since the average thickness of the TiO$_2$ layer on the edge of the g-C$_3$N$_4$ is ~3.1 nm and the average diameter of the TiO$_2$ nanoparticles on the surface of the g-C$_3$N$_4$ is ~6.3 nm, the growth rate of ALD TiO$_2$ was calculated to be 0.15 Å per cycle, which is similar to reported growth rates for ALD TiO$_2$ thin film grown with TTIP and H$_2$O at 250 °C (0.15–0.3 Å per cycle). EDS line scan was performed downward through the red line in Fig. 2d (Fig. 2f), which confirmed the growth behavior of ALD TiO$_2$ on the g-C$_3$N$_4$ substrate: layer growth at the edge of g-C$_3$N$_4$ and particle-like growth on the g-C$_3$N$_4$ surface. This growth behavior takes place because the growth of ALD TiO$_2$ only occurs at chemically active defect sites, such as at a few surface defects and line defects at the edge of the g-C$_3$N$_4$. A similar phenomenon was also observed in various ALD studies on carbon nanotubes and graphene. Sun et al. examined ALD of TiO$_2$ on graphene surfaces with very low reactivity. Their results were similar to our work; the surface defects of graphene acted as TiO$_2$ nucleation sites. Additionally, Cavanagh et al. coated Al$_2$O$_3$ on multi-walled carbon nanotubes (MWCNT) using ALD and found that Al$_2$O$_3$ nucleation only occurred at a few defects and active chemical species on the surface of the MWCNT. g-C$_3$N$_4$ has many defects consisting of NH and NH$_2$ functional groups, which facilitate nucleation during the ALD process.
Furthermore, the reaction between C–NH₂ and H₂O produces OH functional groups.²⁹,³² Therefore, the nucleation of TiO₂ occurs on the NH, NH₂, and OH functional groups at the defect sites on the surface and edge of g-C₃N₄, as shown in Fig. 2g. Furthermore, IR spectra of the prepared samples indicate that the change of defect site on g-C₃N₄ occurred with increasing number of ALD TiO₂ cycles as shown in Fig. 2h. The broad absorption band in the region of 3000–3400 cm⁻¹ corresponds to the stretching mode of the terminal NH₂, NH, and OH surface active species.³⁵ The absorption peaks between 1200 and 1630 cm⁻¹ are assigned to the stretching modes of CN heterocycles. The peak at 805 cm⁻¹ is attributed to the characteristic mode of the triazine unit.³³ In all cases, these peaks confirm the presence of g-C₃N₄. Note that the peak intensity in the region of 3000–3400 cm⁻¹ corresponding to the surface active species decreased with an increasing number of ALD cycles, which suggests that the surface active species were consumed by ALD TiO₂ growth, as discussed above.

The band gap energy of GCN, GT2, GT5, GT50, and GT200 were obtained based on UV-Vis diffuse reflectance spectra, and the results were similar (~2.75 eV) regardless of number of ALD cycle (Fig. S2†). Since the band gap energy of TiO₂ (~3.21 eV) is larger than that of g-C₃N₄ (~2.75 eV), TiO₂ loading on the g-C₃N₄ has a minimal effect on the observed band gap energy of g-C₃N₄@TiO₂ composite.

Fig. 3a shows the degradation of the RhB dye concentration in the presence of GCN, GTs, GTC, and pure TiO₂ (P25) as a function of time exposed to visible light irradiation. All the samples exhibited photocatalytic activity under visible light irradiation. The photolysis of RhB dyes in the absence of the photocatalysts under visible light is also included, which was negligible. For GCN, 71% of the RhB was decomposed under visible light irradiation after 2 h. Even though it is generally known that pure TiO₂ is not capable of absorbing visible light, the pure TiO₂ (P25) that we used for comparison removed 32% of RhB dye molecules due to dye sensitization of the RhB adsorbed on the TiO₂ surface, which is in agreement with previous studies.²⁴ RhB dye can generate e⁻–h⁺ pairs by absorbing light. Then, the photo-generated electrons are injected into the TiO₂ conduction band. The injected electrons reduce O₂ to superoxide O₂⁻⁻, which contributes to the decomposition of the RhB dye molecules. For quantitative analysis of the photocatalytic activity, a pseudo-first-order kinetics model was employed according to Langmuir–Hinshelwood using the following equation:

\[
\ln\left(\frac{C}{C_0}\right) = kt
\]

where \( k \), \( C_0 \), and \( C \) are the apparent reaction rate constant, original concentration, and instantaneous concentration of RhB, respectively. Fig. 3b presents the apparent reaction rate constant of the prepared samples. While GCN and pure TiO₂ (P25) exhibited the rate constant of 0.0102 min⁻¹ and 0.00324 min⁻¹, respectively, all the GTs showed higher reaction rate constants than GCN. When the number of ALD cycles increased from 2 (GT2) to 5 (GT5), the reaction rate constant abruptly increased to the maximum observed value of 0.0316 min⁻¹, which then decreased gradually for higher numbers of ALD cycles (GT5 > GT20 > GT50 > GT200 > GT2). The reaction rate constant of GTC (0.0154 min⁻¹) was similar with that of GT200 (0.01456 min⁻¹).

For a better comparison, however, it is necessary to control the concentration of g-C₃N₄ in the GTs to be identical or normalized because bare TiO₂ rarely absorbs visible light due to its large energy band gap. Fig. 3c shows the weight concentration of g-C₃N₄ in the GTs as a function of the number of ALD cycles based on the N/Ti values measured by SEM-EDS. In the figure, the g-C₃N₄ concentration decreased from 98.4% to 48.1% when the number of ALD cycles increased from 2 (GT2) to 200 (GT200). Therefore, the photocatalytic reaction rate constant was normalized to the weight concentration of g-C₃N₄.
in the GTs, as shown in Fig. 3d. The saturation trend of the normalized rate constant was observed after 5 ALD cycles. Such an important observation suggests that only 5 cycles of TiO$_2$ ALD are required to reach to the saturated photocatalytic reaction rate constant. The origin of such a behavior was examined as follows. The photocatalytic reaction rate is mainly determined by the charge recombination behavior and specific surface area of the GTs. First, the charge recombination behavior was examined using the photoluminescence (PL) in Fig. 3e. Since PL emissions result from the recombination of excited e$^-$–h$^+$ pairs, PL is generally used to study the state of photo-generated carriers. The higher the recombination of the charge carriers occurred, the higher the PL emission intensity was observed. GCN exhibited the highest PL intensity, suggesting that the charge recombination rate is the largest, and thus, GCN has the lowest photoactivity. The decrease in the PL intensity of the GTs compared to GCN indicates that photo-induced electrons from g-C$_3$N$_4$ are transferred to TiO$_2$, which leads to efficient charge separation.$^{25,26}$ The PL intensity decreased abruptly when the number of ALD cycles increased from 2 (GT2) to 5 (GT5), and gradually saturated over 5 ALD cycles. Therefore, 5 cycles of ALD with TiO$_2$ are enough to form intimate heterojunctions with g-C$_3$N$_4$ for efficient charge separation. Secondly, as shown in Fig. 3f, the specific surface area (BET) of the GTs increased when TiO$_2$ was coated on the g-C$_3$N$_4$ surface in a three-dimensional manner, but it was saturated over 5 ALD cycles because the average pore diameter in the GTs decreased with an increasing number of TiO$_2$ ALD cycles. Consequently, the PL emission and BET results in Fig. 3e and f, respectively, coincide with the normalized photocatalytic activity results in Fig. 3d; the reaction rate constant was saturated over 5 ALD cycles. On the other hand, GTC exhibited a specific surface area similar to that of GCN and showed intermediate PL intensity because the TiO$_2$ particles were mechanically agglomerated onto the g-C$_3$N$_4$ without intimate contact to form heterojunctions. As a result, GTC displayed poor photocatalytic activity (the g-C$_3$N$_4$ concentration in GTC is $\sim$89%). Meanwhile, the saturation behaviour of photocatalytic activity might be also associated with charge carrier recombination at the interface under the overload of ALD TiO$_2$ exceeding the optimal value.$^{26}$

The photocatalytic reaction mechanism was examined using active species trapping (scavenger) experiments. BQ,$^{57}$ EDTA-2Na,$^{57}$ and IPA$^{58}$ were used to trap O$_2^-$, h$^+$ and 'OH, respectively. Fig. 4a and b present the results of the scavenger experiments associated with GCN and GT5, respectively. The slowest degradation rate of RhB was observed in the presence of BQ for GCN, suggesting that O$_2^-$ plays a key role for photodegradation. The degradation rate of RhB in the presence of IPA was 69%, similar to the results observed without the scavenger, implying that 'OH has a minor role for RhB dye degradation. On the other hand, in the presence of EDTA-2Na, the degradation of the RhB dye reached 99% within 100 min. In this case, it is expected that EDTA-2Na promoted charge separation in the g-C$_3$N$_4$ by trapping h$^+$ which has minimal involvement in the decomposition reaction of RhB, thus enhancing the degradation of RhB.$^{57,59}$

In Fig. 4b, the lowest photocatalytic activity of GT5 in the presence of BQ confirmed that O$_2^-$ was a major active species for RhB dye degradation, similar to GCN. However, in the presence of IPA, the photocatalytic activity of GT5 decreased significantly, while the change in the photocatalytic activity of GCN with IPA was negligible. Such a result suggests that the contribution of 'OH to the photocatalytic
reaction increased when ALD TiO2 was adopted on g-C3N4. This result can be explained with the behaviors of the active species and the charge separation in the heterojunctions. g-C3N4, with an energy band gap of 2.87 eV, is capable of absorbing visible light with a wavelength over 450 nm, but TiO2 does not typically utilize visible light due to its wide energy band gap. Therefore, electrons are photo-generated in g-C3N4 to form the superoxide radical (O2•−) by reacting with O2 (−0.28 V) according to reaction (1), which is the main active species for the photocatalytic degradation of both GCN and GTs as discussed above.

\[ \text{e}^- + \text{O}_2 \rightarrow \text{O}_2^{•-} \quad (0.28 \text{ V}) \tag{1} \]

For GTs, the lowest unoccupied molecular orbital (LUMO) and highest occupied molecular orbital (HOMO) levels (−1.27 and 1.55 eV) of g-C3N4 are more negative than the conduction band and valence band edge (−0.5 and 1.99 eV) of TiO2, which produces the type II heterojunction, as shown in Fig. 4c. Photo-generated electrons in g-C3N4 are injected from the LUMO level of g-C3N4 to the conduction band of TiO2, while photo-generated holes remain in the g-C3N4 (charge separation). Therefore, carrier recombination is suppressed, and more superoxide radicals (O2•−) are generated compared to GCN, which contribute to the formation of the hydroxyl radical (‘OH), another active species, through reactions (2) and (3) in a sequence (0.305 and 0.67 V, respectively). The redox potential of all the reactions [(1)–(3)] are more positive than the conduction band of TiO2, which suggests that these reactions are thermodynamically favorable. Therefore, the hydroxyl radical became a secondary active species for RhB degradation in the GTs.

\[ \text{O}_2^{•-} + 2\text{H}^+ \rightarrow \text{H}_2\text{O}_2 (0.305 \text{ V}) \tag{2} \]
\[ \text{H}_2\text{O}_2 + \text{e}^- \rightarrow \text{OH}^- + \cdot\text{OH} (0.67 \text{ V}) \tag{3} \]

Photo-generated holes in g-C3N4 have minimal involvement in photocatalytic reactions due to similar HOMO levels between g-C3N4 (1.55 V) and RhB (1.43 V). Hydroxyl radical formation from the reaction of the holes with H2O is also implausible, because the redox potential of OH−/‘OH (1.99 V) is more positive than the HOMO level of g-C3N4.

4. Conclusions

In summary, TiO2 was coated on g-C3N4 using ALD to control the recombination rate of photo-generated charge carriers in g-C3N4 (g-C3N4@ALD-TiO2). g-C3N4@TiO2 composites synthesized by a simple impregnation method were also prepared and used for comparison against the proposed method. When using ALD, TiO2 nanoparticles with a diameter of ~6 nm were homogeneously distributed on the g-C3N4 surface. On the other hand, the impregnation method resulted in TiO2 agglomerates on the surface of the g-C3N4. The photocatalytic activity of the g-C3N4@ALD-TiO2 composites was estimated using the photocatalytic degradation of RhB under visible light irradiation. Five cycles of TiO2 ALD was enough to form intimate, stable, and uniform heterojunctions on g-C3N4 and enhance the photocatalytic activity, as demonstrated by the saturation of the normalized photocatalytic reaction rate constant. With respect to the surface area of a composite, 5 is also an optimal number of ALD cycles. The photocatalytic reaction rate constant was 3 times higher than that of the bare g-C3N4 and 2 times higher than that of the composite prepared by the simple impregnation method.

Conflicts of interest

TP and YP conceived and designed the experiments. EJ and WK conducted most of the experiments. DK, SH and IA performed the data analysis. TP, YP and EJ co-wrote the paper. All authors discussed the results and commented on the manuscript.

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